

BC516

PNP Darlington Transistor

- This device is designed for applications reguiring extremely high current gain at currents to 1mA.
- Sourced from process 61.



1. Collector 2. Base 3. Emitter

Absolute Maximum Ratings $T_A=25$ °C unless otherwise noted

Symbol	Parameter	Value	Units	
V _{CEO}	Collector-Emitter Voltage	30	V	
V _{CBO}	Collector-Base Voltage	40	V	
V _{EBO}	Emitter-Base Voltage	10	V	
I _C	Collector Current - Continuous	1	Α	
P_{D}	Total Power Dissipation T _A = 25°C	625	mW	
T _J , T _{STG}	Operating and Storage Junction Temperature Range	-55 ~ +150	°C	

Electrical Characteristics T_A=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
V _{CEO}	Collector-Emitter Breakdown Voltage	$I_C = 2mA$, $I_B = 0$	30			V
V _{CBO}	Collector-Base Breakdown Voltage	$I_C = 100 \mu A, I_E = 0$	40			V
V _{EBO}	Emitter-Base Breakdown Voltage	$I_E = 10\mu A, I_C = 0$	10			V
I _{CBO}	Collector Cutoff Current	$V_{CB} = 30V, I_{E} = 0$			100	nA
h _{FE}	DC Current Gain	I _C = 20mA, V _{CE} = 2V	30,00			
			0			
V _{CE} (sat)	Collector-Emitter Saturation Voltage	$I_C = 100 \text{mA}, I_B = 0.1 \text{mA}$			1	V
V _{BE} (on)	Base-Emitter On Voltage	I _C = 10mA, V _{CE} = 5V			1.4	V
f _T	Current Gain Bandwidth Product (2)	$I_C = 10 \text{mA}, V_{CE} = 5 \text{V}, f = 100 \text{MHz}$		200		MHz

NOTES:

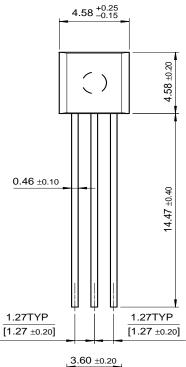
Thermal Characteristics $T_A=25$ °C unless otherwise noted

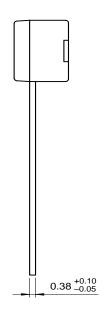
Symbol	Parameter	Max.	Units
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	°C/W
$R_{\theta JC}$	Thermal Resistance, Junction to Case		°C/W

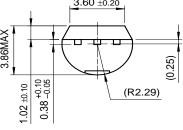
Pulse Test Pulse Width ≤ 2%
f_T = Ih_{fe}I · f_{test}

Package Dimensions

TO-92







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